# BUJ100LR

## NPN power transistor

Rev. 02 — 29 July 2010

**Product data sheet** 

### 1. Product profile

#### 1.1 General description

High voltage, high speed, planar passivated NPN power switching transistor in a SOT54 (TO-92) 3 leads plastic package.

#### **1.2 Features and benefits**

Fast switching

#### **1.3 Applications**

- Compact fluorescent lamps (CFL)
- Electronic lighting ballasts

#### 1.4 Quick reference data

- High voltage capability of 700 V
- Inverters
- Off-line self-oscillating power supplies

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>C</sub>	collector current	DC; see Figure 2	-	-	1	А
P <sub>tot</sub>	total power dissipation	T <sub>lead</sub> ≤ 25 °C; see <u>Figure 1</u>	-	-	2.1	W
V <sub>CESM</sub>	collector-emitter peak voltage	$V_{BE} = 0 V$	-	-	700	V
Static cha	aracteristics					
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_C = 0.8 \text{ A};$ $T_{lead} = 25 \text{ °C}; \text{ see } \underline{Figure 8};$ see $\underline{Figure 9}$	5	7.5	20	



## 2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		
2	С	collector		C
3	E	emitter		B – E sym123
			SOT54 (TO-92)	

## 3. Ordering information

Table 3. Orderin	g information		
Type number	Package		
	Name	Description	Version
BUJ100LR	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54

## 4. Limiting values

#### Table 4.Limiting values

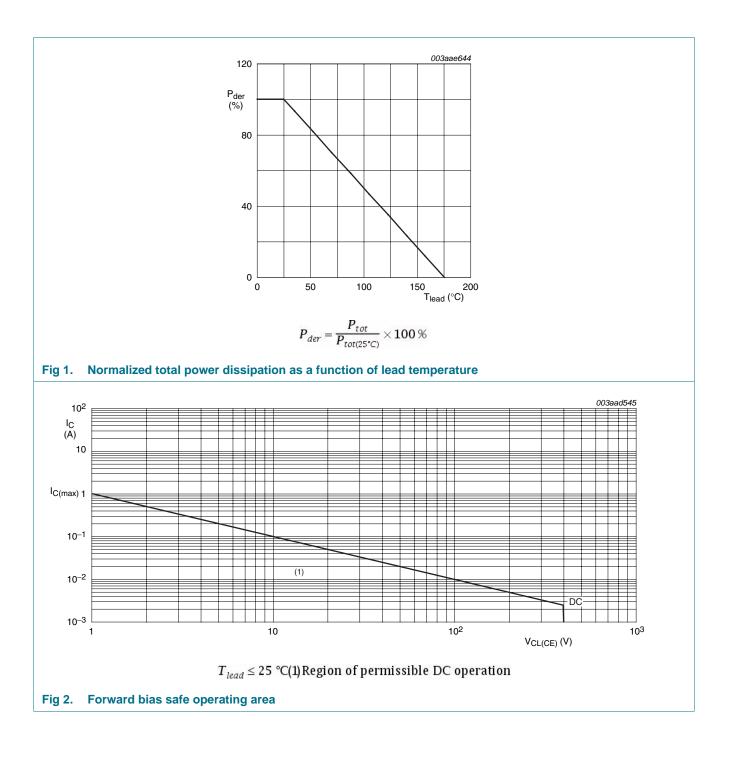
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CESM</sub>	collector-emitter peak voltage	$V_{BE} = 0 V$	-	700	V
V <sub>CBO</sub>	collector-base voltage	I <sub>E</sub> = 0 A	-	700	V
V <sub>CEO</sub>	collector-emitter voltage	I <sub>B</sub> = 0 A	-	400	V
I <sub>C</sub>	collector current	DC; see Figure 2	-	1	А
I <sub>CM</sub>	peak collector current		-	2	А
I <sub>B</sub>	base current	DC	-	0.5	А
I <sub>BM</sub>	peak base current		-	1	А
P <sub>tot</sub>	total power dissipation	T <sub>lead</sub> ≤ 25 °C; see <u>Figure 1</u>	-	2.1	W
T <sub>stg</sub>	storage temperature		-65	150	°C
Tj	junction temperature		-	150	°C
V <sub>EBO</sub>	emitter-base voltage	$I_{C} = 0 \text{ A}$ ; I(Emitter) = 10 mA	-	9	V

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## **BUJ100LR**

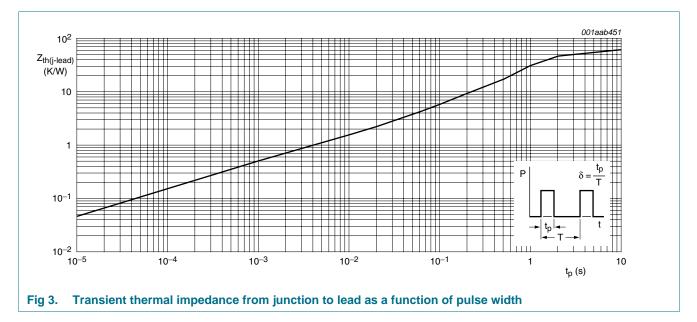
**NPN** power transistor



**NPN** power transistor

## 5. Thermal characteristics

Table 5.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	see Figure 3	-	-	60	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	printed-circuit board mounted; lead length 4 mm	-	150	-	K/W

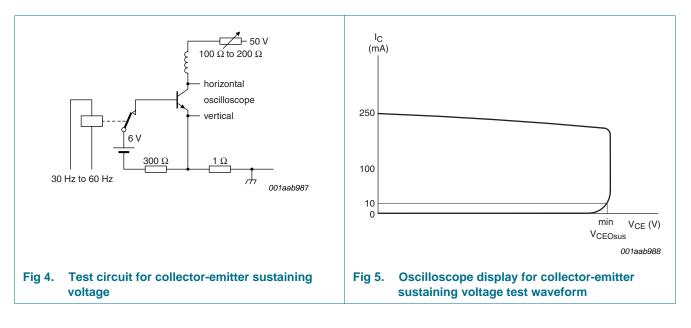


**NPN** power transistor

### 6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I <sub>CES</sub>	collector-emitter cut-off current	$V_{BE}$ = 0 V; $V_{CE}$ = 700 V; $T_j$ = 125 °C	-	-	5	mA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB}$ = 9 V; I <sub>C</sub> = 0 A; T <sub>lead</sub> = 25 °C	-	-	1	mA
V <sub>CEOsus</sub>	collector-emitter sustaining voltage	$I_B = 0 A$ ; $I_C = 1 mA$ ; $L_C = 25 mH$ ; $T_{lead} = 25 \text{ °C}$ ; see <u>Figure 4</u> ; see <u>Figure 5</u>	400	-	-	V
OLGAI	collector-emitter saturation voltage	$I_{C}$ = 0.25 A; $I_{B}$ = 50 mA; $T_{lead}$ = 25 °C; see <u>Figure 6</u>	-	0.2	0.5	V
		$I_C = 0.5 \text{ A}; I_B = 125 \text{ mA}; T_{\text{lead}} = 25 \text{ °C};$ see Figure 6	-	0.3	1	V
		$I_{C}$ = 0.75 A; $I_{B}$ = 250 mA; $T_{lead}$ = 25 °C; see <u>Figure 6</u>	-	0.4	1.5	V
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{C}$ = 0.25 A; $I_{B}$ = 50 mA; $T_{lead}$ = 25 °C; see <u>Figure 7</u>	-	-	1	V
		$I_{C}$ = 0.5 A; $I_{B}$ = 125 mA; $T_{lead}$ = 25 °C; see Figure 7	-	-	1.2	V
h <sub>FE</sub>	DC current gain	$I_{C}$ = 0.5 mA; $V_{CE}$ = 2 V; $T_{lead}$ = 25 °C	12	-	-	
		$I_{C} = 0.4 \text{ A}; V_{CE} = 5 \text{ V}; T_{lead} = 25 \text{ °C};$ see <u>Figure 8</u> ; see <u>Figure 9</u>	10	-	30	
		$I_C = 0.8 \text{ A}; V_{CE} = 5 \text{ V}; T_{lead} = 25 \text{ °C};$ see <u>Figure 8</u> ; see <u>Figure 9</u>	5	7.5	20	
Dynamic	characteristics					
t <sub>f</sub>	fall time	I <sub>C</sub> = 1 A; I <sub>Bon</sub> = 200 mA; V <sub>BB</sub> = -5 V;	-	80	-	ns

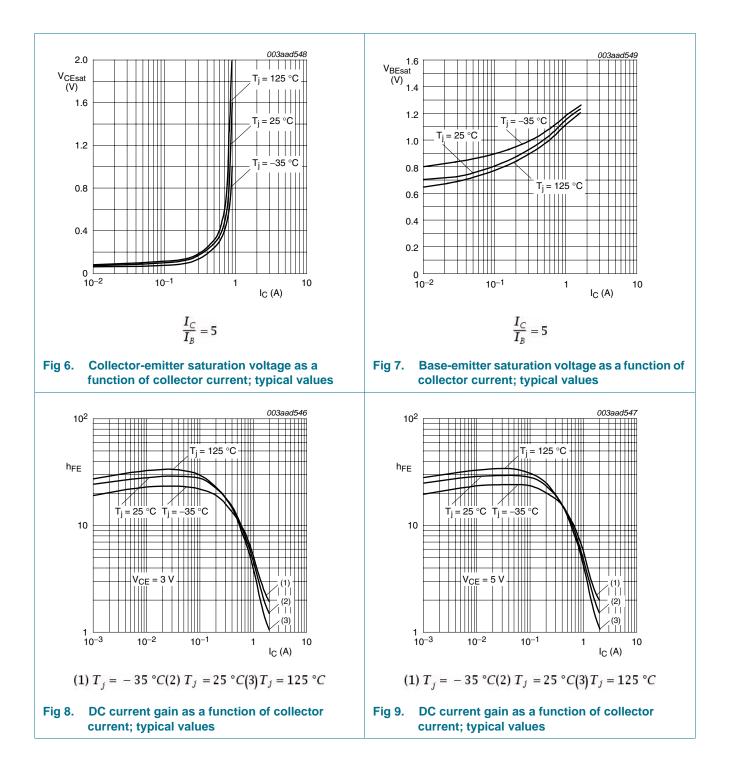
#### fall time $I_C = 1 A$ ; $I_{Bon} = 200 mA$ ; $V_{BB} = -5 V$ ; - 80 - ns $L_B = 1 \mu H$ ; $T_{lead} = 25 °C$ ; inductive load; see Figure 10; see Figure 11



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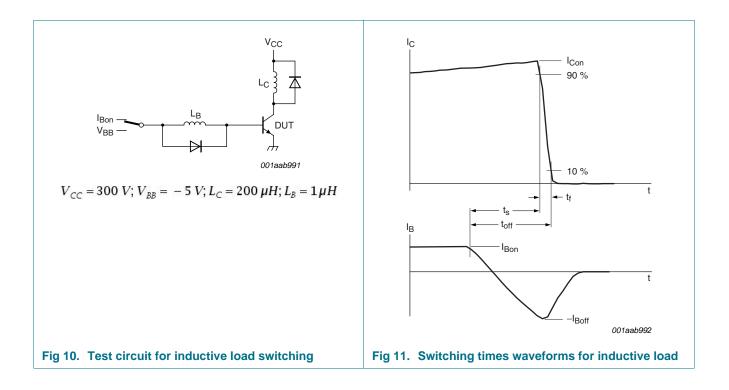
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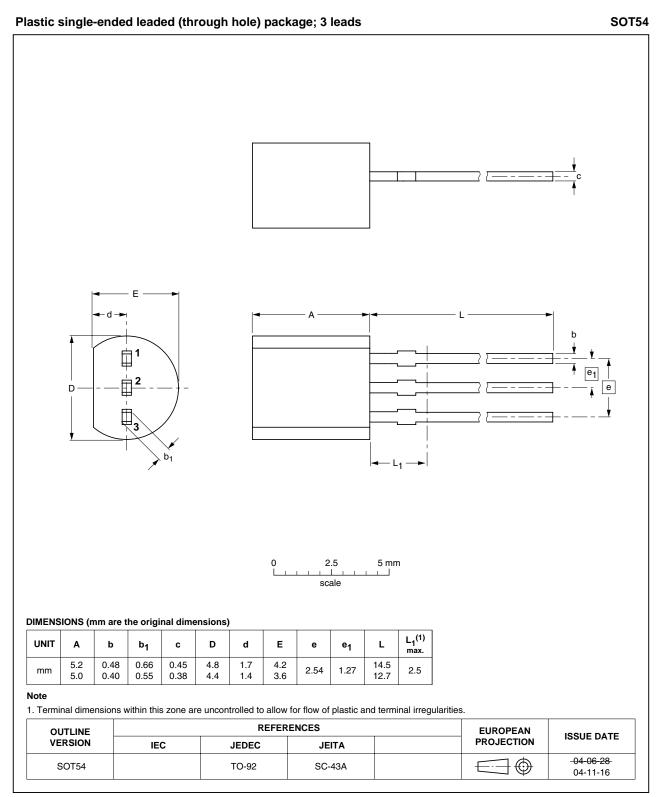
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### 7. Package outline



#### Fig 12. Package outline SOT54 (TO-92)

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NPN power transistor

## 8. Revision history

Table 7.Revision	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BUJ100LR v.2	20100729	Product data sheet	-	BUJ100LR v.1
Modifications:	<ul> <li>Various chang</li> </ul>	es to content.		
BUJ100LR v.1	20090812	Product data sheet	-	-

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#### 9.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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## **BUJ100LR**

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